

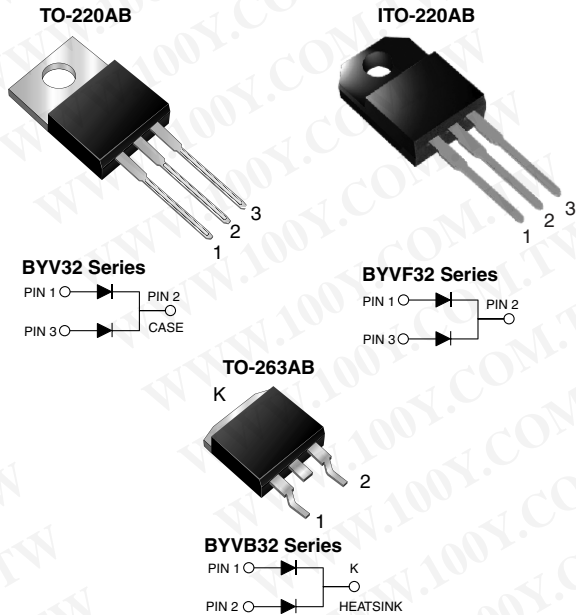


勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

BYV(F,B)32-50 thru BYV(F,B)32-200

Vishay General Semiconductor

Dual Common-Cathode Ultrafast Rectifier



FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	18 A
V_{RRM}	50 V to 200 V
I_{FSM}	150 A
t_{rr}	25 ns
V_F	0.85 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_C = 125$ °C	$I_{F(AV)}$	18				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150				A
Operating storage and temperature range	T_J, T_{STG}	- 65 to + 150				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1$ min	V_{AC}	1500				V

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 20 A I _F = 5.0 A	T _J = 100 °C	V _F			1.15 0.85		V
Maximum DC reverse current per diode at rated DC blocking voltage		T _J = 25 °C T _J = 100 °C	I _R			10 600		μA
Maximum reverse recovery time per diode	I _F = 1 A, V _R = 30 V, dI/dt = 100 A/μs, I _{rr} = 10 % I _{RM}		t _{rr}			25		ns
Typical junction capacitance per diode	4.0 V, 1 MHz		C _J			45		pF

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	BYV	BYVF	BYVB	UNIT
Typical thermal resistance from junction to case per diode	R _{θJC}	1.6	5.0	1.6	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape reel
TO-220AB	BYV32-200HE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200HE3/45 ⁽¹⁾	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/81 ⁽¹⁾	1.35	81	800/reel	Tape reel

Note:

(1) Automotive grade AEC Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

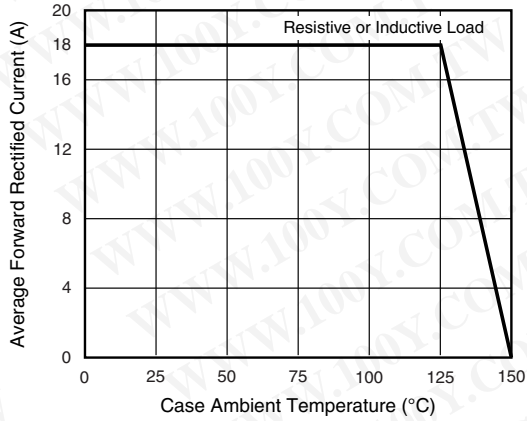


Figure 1. Forward Current Derating Curve

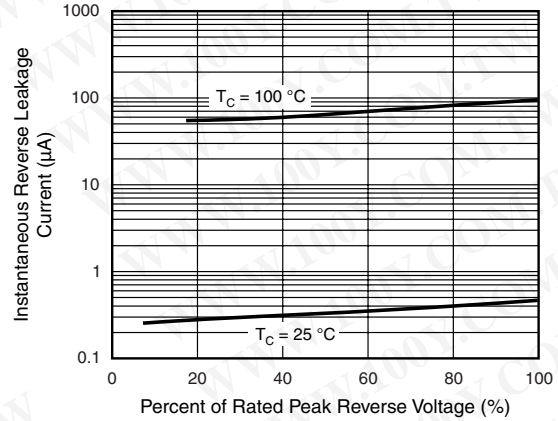


Figure 4. Typical Reverse Leakage Characteristics Per Diode

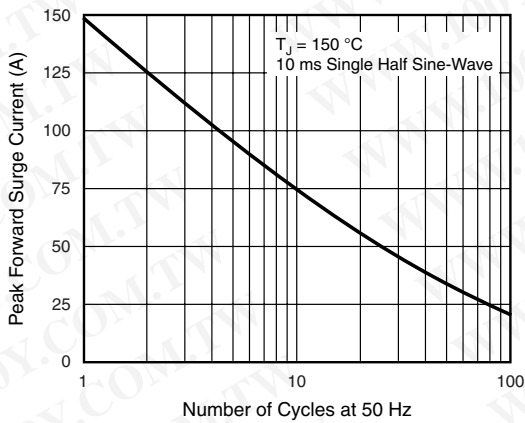


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

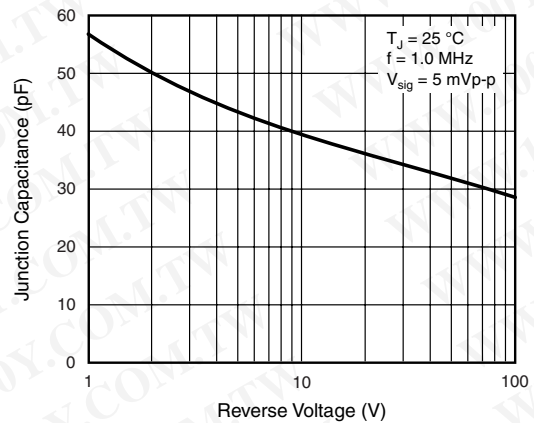


Figure 5. Typical Junction Capacitance Per Diode

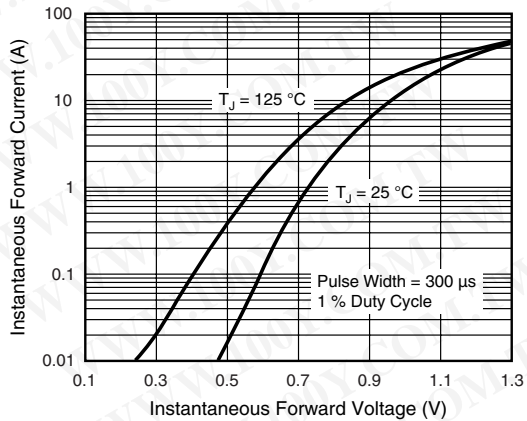


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

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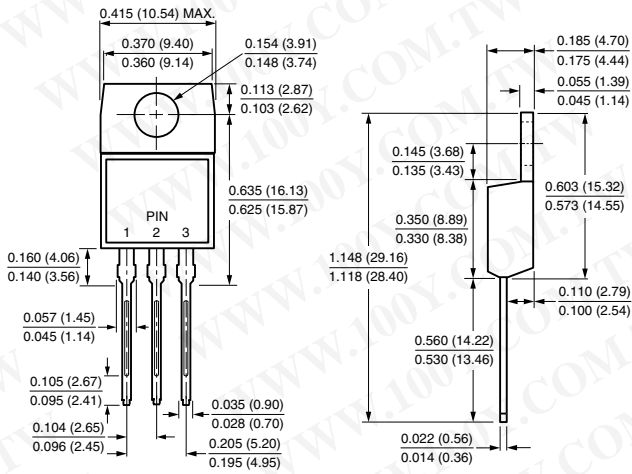
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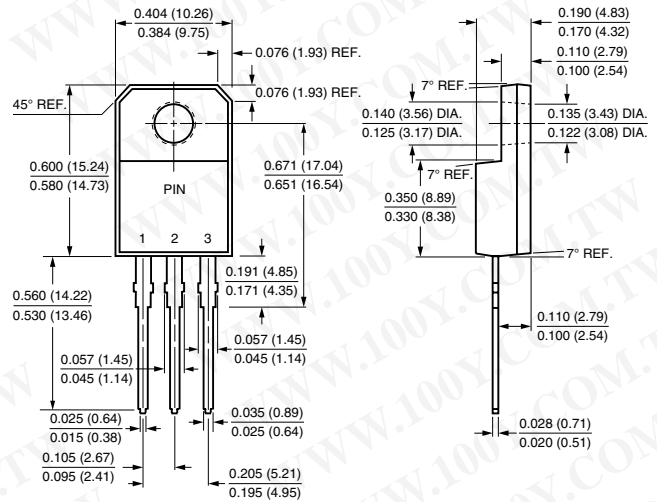


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

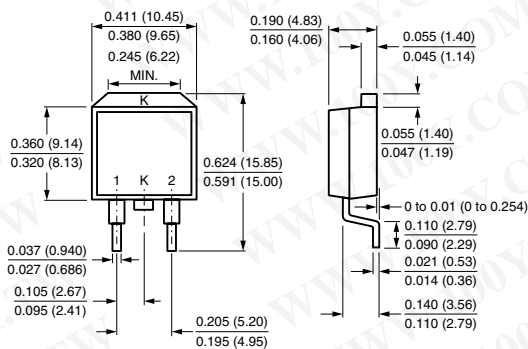
TO-220AB



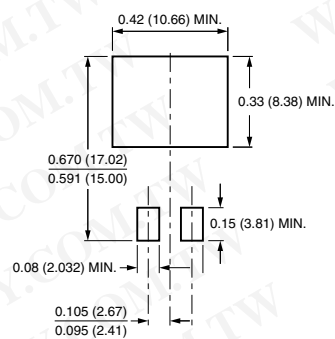
ITO-220AB



TO-263AB



Mounting Pad Layout



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